

No.783B

**LB1272**

Monolithic Digital IC

**SANYO****6-Unit, Darlington Transistor Array**

The circuit configuration of this IC is a 6-unit Darlington transistor array consisting of NPN transistors and is ideally suited for use in printer hammer driving, lamp or relay driving applications.

With the built-in protective diodes against negative inputs, this IC offers advantages to the driver circuit design of electronic calculator with printer and cash register, etc. which also use display tubes.

**Features**

- Ideally suited for 18-digit printer because of built-in 6 units.
- With built-in protective diodes against negative inputs.
- Ideally suited for printer mechanism with load current 85 mA.

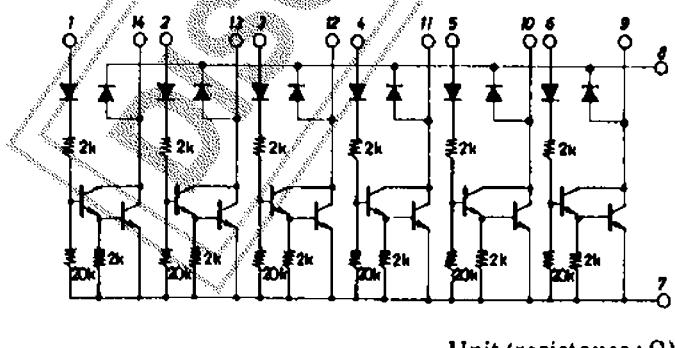
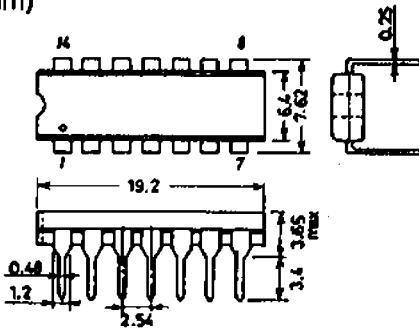
**Absolute Maximum Ratings at  $T_a=25^\circ\text{C}$** 

Output Supply Voltage	V <sub>OUT</sub>	-0.3 to +22	unit
Input Supply Voltage	V <sub>IN</sub>	-40 to +12	V
Pin 8 Supply Voltage	V <sub>CC</sub>	-0.3 to +20	V
Output Flow-in Current	I <sub>OUT</sub>	100	mA
Instantaneous Output	I <sub>OP</sub>	160	mA
Flow-in Current	Per unit Per unit, duty=10% Pulse width<20ms		
Spark Killer Diode Forward Current	I <sub>F(S)</sub>	160	mA
GND Pin Flow-out Current	I <sub>GP</sub>	-900 to 0	mA
Pin 8 Instantaneous Flow-out Current	I <sub>CCP</sub>	-900 to 0	mA
Current	"		
Pin 8 Flow-out Current	I <sub>CC</sub>	-600 to 0	mA
Allowable Power Dissipation	P <sub>d</sub> max	770	mA
Operating Temperature	T <sub>opr</sub>	-20 to +80	°C
Storage Temperature	T <sub>stg</sub>	-40 to +125	°C

**Allowable Operating Conditions at  $T_a = 25^\circ\text{C}$** 

Output Supply Voltage	V <sub>OUT</sub>	22	unit
Input High Level Voltage	V <sub>IH</sub>	3 to 12	V max
Input Low Level Voltage	V <sub>IL</sub>	-35 to +1	V
Load Inductance	L <sub>L</sub>	100	mH max

(Continued on next page)

**Equivalent Circuit****Package Dimensions 3003A**  
(unit : mm)

**SANYO Electric Co., Ltd. Semiconductor Business Headquarters**  
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

**Operating Characteristics at  $T_a=25^\circ\text{C}$** 

			min	typ	max	unit
Output Voltage	$V_{\text{OUT}}(1)$	$V_{\text{IN}}=3\text{V}, I_{\text{OUT}}=150\text{mA}$			1.7	V
	$V_{\text{OUT}}(2)$	$V_{\text{IN}}=3\text{V}, I_{\text{OUT}}=100\text{mA}$			1.4	V
Output Sustain Voltage	$V_{\text{OUT}}(s)$	$V_{\text{IN}}=\text{open}, I_{\text{OUT}}=150\text{mA}$ Applied time < $10\mu\text{s}$	22			V
Output Leakage Current	$I_{\text{off}}$	$V_{\text{IN}}=1\text{V}, V_{\text{out}}=22\text{V}$			100	$\mu\text{A}$
Input Current	$I_{\text{IN}}$	$V_{\text{IN}}=3\text{V}$			1	$\text{mA}$
Output Current	$I_{\text{OUT}}$	$I_{\text{IN}}=0.3\text{mA}, V_{\text{OUT}}=1.4\text{V}$			100	$\text{mA}$
Input Leakage Current	$I_{\text{leak}}$	$V_{\text{IN}}=-35\text{V}$			-10	$\mu\text{A}$
Spark Killer Diode Leakage Current	$I_{\text{leak(s)}}$	$V_{\text{OUT}}=0\text{V}, \text{Pin8}=20\text{V}$			30	$\mu\text{A}$
Spark Killer Diode Forward Voltage	$V_{\text{F(S)}}$	$I_{\text{F(3)}}=150\text{mA}$			1.7	V

